

Features

- Low Gate Charge
- Low $R_{DS(ON)}$:
 - 33 m Ω @ $V_{GS} = 10V$
 - 40 m Ω @ $V_{GS} = 4.5V$
- Low Input/Output Leakage
- **Lead Free By Design/RoHS Compliant (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**
- **"Green" Device (Note 4)**

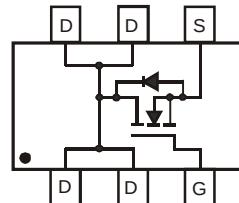
Mechanical Data

- Case: SOT-26
- Case Material - Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020D
- Terminals: Finish – Matte Tin annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208
- Terminal Connections: See Diagram
- Marking Information: See Page 4
- Ordering Information: See Page 4
- Weight: 0.008 grams (approximate)

SOT-26



TOP VIEW



Equivalent Circuit

Maximum Ratings @ $T_A = 25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	Value	Unit
Drain-Source Voltage	V_{DS}	30	V
Gate-Source Voltage	V_{GS}	± 20	V
Drain Current (Note 1) Continuous	I_D	6.9	A
$T_A = 25^\circ\text{C}$		5.8	
$T_A = 70^\circ\text{C}$			
Pulsed Drain Current (Note 2)	I_{DM}	20	A
Body-Diode Continuous Current (Note 1)	I_S	2.25	A

Thermal Characteristics @ $T_A = 25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 1)	P_D	2	W
Thermal Resistance, Junction to Ambient (Note 1) $t \leq 10s$	$R_{\theta JA}$	62.5	$^\circ\text{C/W}$
Operating and Storage Temperature Range	T_J, T_{STG}	-55 to +150	$^\circ\text{C}$

- Notes:
1. Device mounted on 1"x1", FR-4 PC board with 2 oz. Copper and test pulse width $t \leq 10s$.
 2. Repetitive Rating, pulse width limited by junction temperature.
 3. No purposefully added lead.
 4. Diodes Inc's "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.

Electrical Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
STATIC CHARACTERISTICS						
Drain-Source Breakdown Voltage	BV _{DSS}	30	—	—	V	I _D = 250μA, V _{GS} = 0V
Zero Gate Voltage Drain Current	I _{DSS}	—	—	1 5	μA	T _J = 25°C T _J = 55°C V _{DS} = 30V, V _{GS} = 0V
Gate-Body Leakage Current	I _{GSS}	—	—	±100	nA	V _{DS} = 0V, V _{GS} = ±20V
Gate Threshold Voltage	V _{GS(th)}	1.0	—	2.1	V	V _{DS} = V _{GS} , I _D = 250μA
Static Drain-Source On-Resistance (Note 5)	R _{DS (ON)}	—	25 36	33 40	mΩ	V _{GS} = 10V, I _D = 6.9A V _{GS} = 4.5V, I _D = 5.0A
Forward Transconductance (Note 5)	g _{FS}	—	5	—	S	V _{DS} = 10V, I _D = 8A
Diode Forward Voltage (Note 5)	V _{SD}	—	0.7	1.1	V	I _S = 2.25A, V _{GS} = 0V
DYNAMIC CHARACTERISTICS (Note 6)						
Input Capacitance	C _{iss}	—	755	—	pF	V _{DS} = 10V, V _{GS} = 0V f = 1.0MHz
Output Capacitance	C _{oss}	—	136	—	pF	
Reverse Transfer Capacitance	C _{rss}	—	108	—	pF	
Gate Resisitance	R _G	—	0.89	—	Ω	V _{GS} = 0V, V _{DS} = 0V, f = 1MHz
SWITCHING CHARACTERISTICS						
Total Gate Charge	Q _g	—	6.4 13.0	—	nC	V _{GS} = 4.5V, V _{DS} = 15V, I _D = 5A V _{GS} = 10V, V _{DS} = 15V, I _D = 6.9A
Gate-Source Charge	Q _{gs}	—	1.9	—	nC	V _{GS} = 10V, V _{DS} = 15V, I _D = 6.9A
Gate-Drain Charge	Q _{gd}	—	3.2	—	nC	V _{GS} = 10V, V _{DS} = 15V, I _D = 6.9A
Turn-On Delay Time	t _{D(on)}	—	11	—	ns	V _{DD} = 15V, V _{GS} = 10V, R _D = 1.8Ω, R _G = 6Ω
Turn-On Rise Time	t _r	—	7	—	ns	
Turn-Off Delay Time	t _{D(off)}	—	63	—	ns	
Turn-Off Fall Time	t _f	—	30	—	ns	

Notes: 5. Test pulse width t = 300ms.
6. Guaranteed by design. Not subject to production testing.

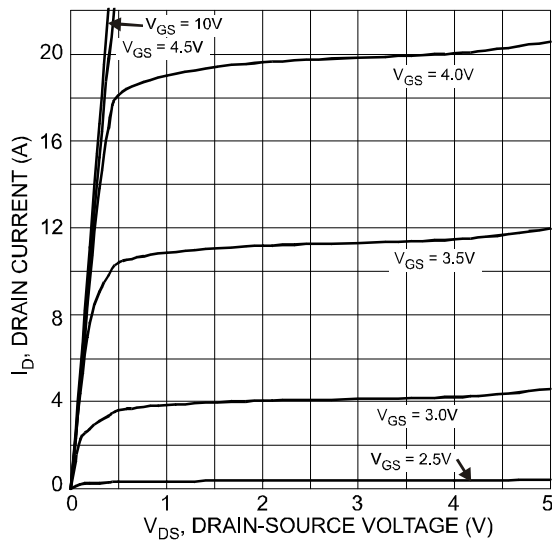


Fig. 1 Typical Output Characteristics

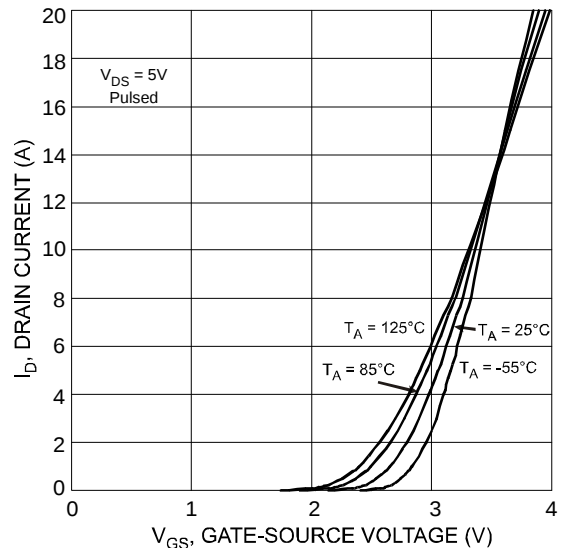


Fig. 2 Typical Transfer Characteristics

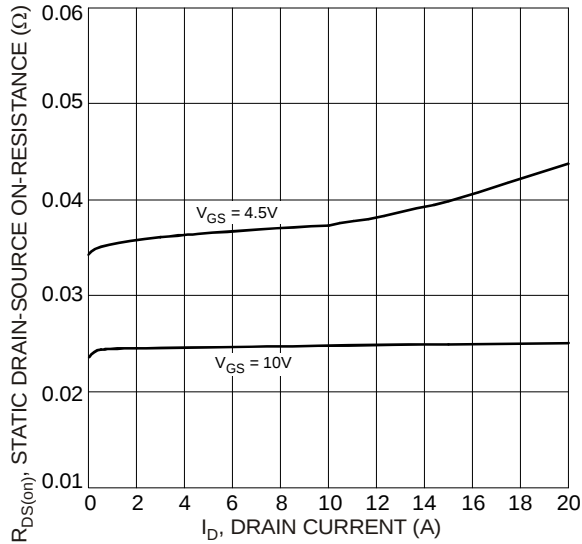


Fig. 3 On-Resistance vs. Drain Current and Gate Voltage

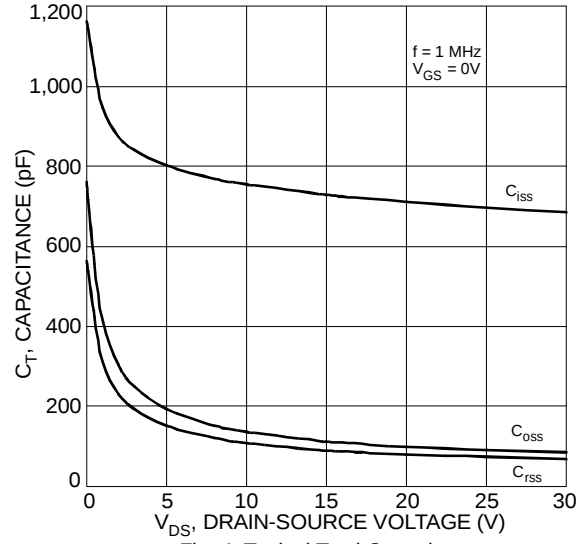


Fig. 4 Typical Total Capacitance

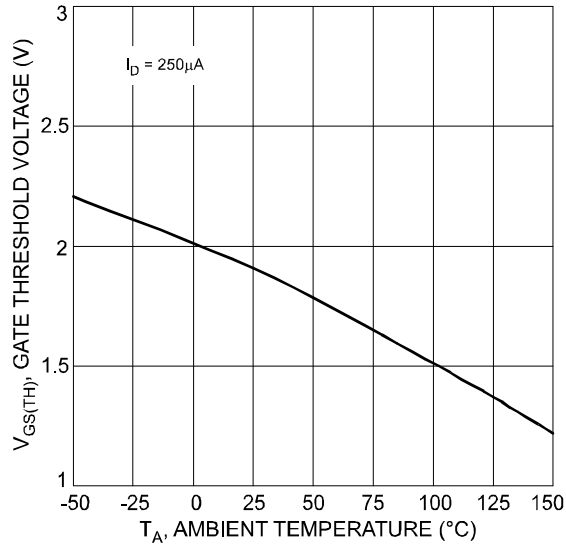


Fig. 5 Gate Threshold Voltage vs. Ambient Temperature

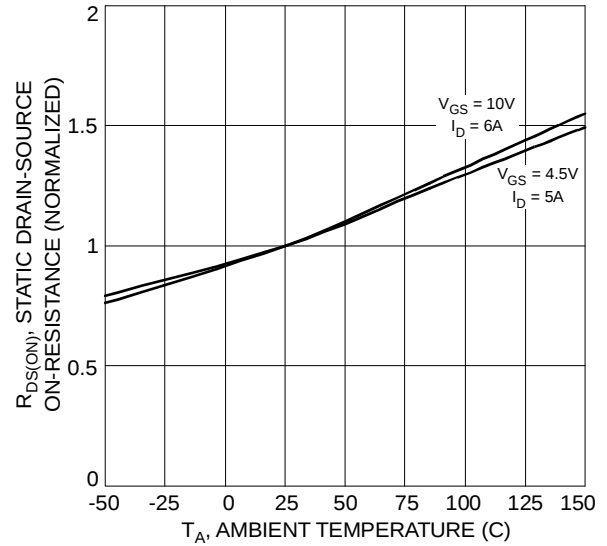


Fig. 6 Normalized Static Drain-Source On-Resistance vs. Ambient Temperature

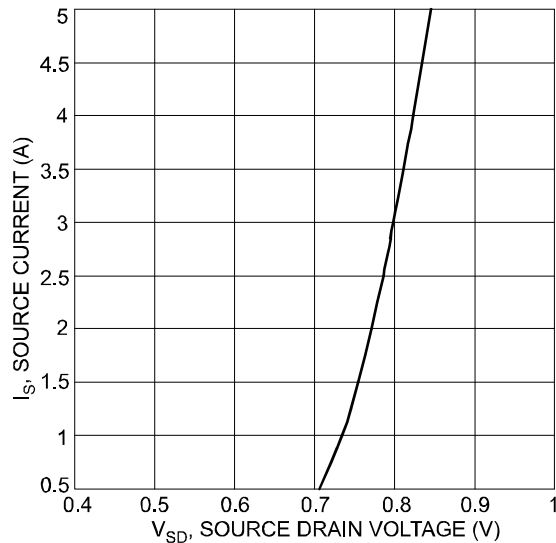


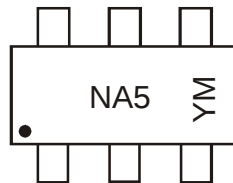
Fig. 7 Reverse Drain Current vs. Source-Drain Voltage

Ordering Information (Note 7)

Part Number	Case	Packaging
DMN3033LDM-7	SOT-26	3000/Tape & Reel

Notes: 7. For packaging details, go to our website at <http://www.diodes.com/datasheets/ap02007.pdf>.

Marking Information



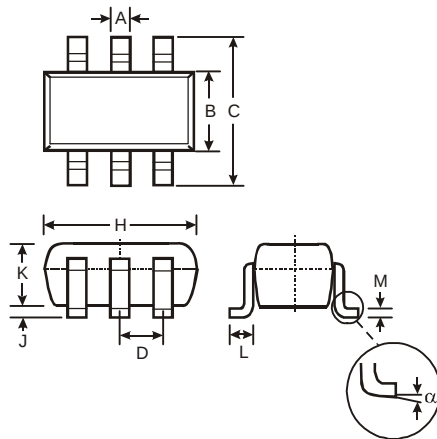
NA5 = Product Type Marking Code
 YM = Date Code Marking
 Y = Year (ex: U = 2007)
 M = Month (ex: 9 = September)

Date Code Key

Year	2007	2008	2009	2010	2011	2012	2013	2014	2015
Code	U	V	W	X	Y	Z	A	B	C

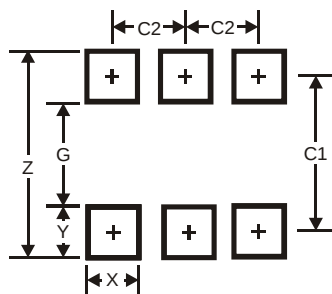
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

Package Outline Dimensions



SOT-26			
Dim	Min	Max	Typ
A	0.35	0.50	0.38
B	1.50	1.70	1.60
C	2.70	3.00	2.80
D	—	—	0.95
H	2.90	3.10	3.00
J	0.013	0.10	0.05
K	1.00	1.30	1.10
L	0.35	0.55	0.40
M	0.10	0.20	0.15
α	0°	8°	—
All Dimensions in mm			

Suggested Pad Layout



Dimensions	Value (in mm)
Z	3.20
G	1.60
X	0.55
Y	0.80
C1	2.40
C2	0.95

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